F Fuji Electric 2MBI600VG-170E

IGBT Modules

IGBT MODULE (V series) 1700V / 600A / 2 in one package

Features

High speed switching Voltage drive Low Inductance module structure

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines

Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items	U (Symbols	Conditions		Maximum ratings	Units	
Collector-Emitter voltage		VCES			1700	V	
Gate-Emitter voltage		V _{GES}			±20		
Collector current		Ic	Continuous	T₀=25°C	800		
			Continuous	Tc=100°C	600		
		ICP	1ms		1200	Α	
		-lc			600		
		- C pulse	1ms		1200		
Collector power dissipation		Pc	1 device		4410	W	
Junction temperature		Tj			175		
Operating junction temperature (under switching conditions)		Tjop			150	°C	
Storage temperature		Tstg			-40 ~ +150		
Isolation voltage	between terminal and copper base (*1)	Viso	AC : 1min.		4000		
	Mounting	-	M6 M8 M4		5.75	N m	
Screw torque (*2)	Main Terminals	-			10		
	Sense Terminals	-			2.5		

Note *1: All terminals should be connected together when isolation test will be done.

Note *2: Recommendable Value : Mounting 4.25~5.75 Nm (M6) , Main Terminals 8~10 Nm (M8) , Sense Terminals 1.7~2.5 Nm (M4) Electrical characteristics (at T = 25°C unless otherwise specified)

Items	Symbols	Conditions		Characteristics			Units
items				min.	typ.	max.	Units
Zero gate voltage collector current	ICES	V _{GE} = 0V, V _{CE} = 1700V		-	-	1.0	mA
Gate-Emitter leakage current	IGES	$V_{CE} = 0V, V_{GE} = \pm 20V$		-	-	1200	nA
Gate-Emitter threshold voltage	VGE (th)	Vce = 20V, Ic = 600mA	6.0	6.5	7.0	V	
	V _{CE (sat)}		Tj=25°C	-	2.18	2.46	V
	(main terminal)		Tj=125°C	-	2.58	-	
Collector-Emitter saturation voltage	(main terminal)	V _{GE} = 15V	Tj=150°C	-	2.63	-	
Conector-Emitter Saturation voltage		Ic = 600A	Tj=25°C	-	2.00	2.25	
	V _{CE (sat)}		Tj=125°C	-	2.40	-	
	(chip)		Tj=150°C	-	2.45	-	
Internal gate resistance	Int RG		-	2.92	-	Ω	
Input capacitance	Cies	Vce = 10V, Vge = 0V, f = 1MH	-	59	-	nF	
Turn-on	ton			-	2.28	-	μs
Turn-on	tr			-	0.86	-	
Turn-off	toff			-	2.07	-	
Turn-on	tr	V _{GE} = ±15V, T _j =125°C	-	0.58	-		
	VF		Tj=25°C	-	1.98	2.36	- V
	(main terminal) V _F (chip)	V _{GE} = 0V I _F = 600A	Tj=125°C	-	2.18	-	
Forward on voltage			Tj=150°C	-	2.16	-	
Forward on voltage			Tj=25°C	-	1.80	2.15	
			Tj=125°C	-	2.00	-	
			Tj=150°C	-	1.98	-	
Reverse recovery	trr	I⊧ = 600A, Tj = 125°C		-	0.31	-	μs
Lead resistance, terminal-chip	R lead			-	0.291	-	mΩ

Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
items		contaitions	min.	typ.	max.	Units
Thermal register co(fdevice)	R _{th(j-c)}	IGBT	-	-	0.034	°C/W
Thermal resistance(1device)		FWD	-	-	0.060	
Contact thermal resistance (1module) (*3)	Rth(c-f)	with Thermal Compound	-	0.006	-	

Note *3: This is the value which is defined mounting on the additional cooling fin with thermal compound.

12V

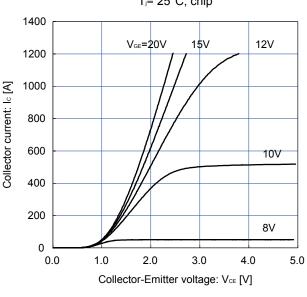
10V

8V

5.0

4.0

Characteristics (Representative)



Collector current vs. Collector-Emitter voltage (typ.) T_j = 25°C, chip

Collector current vs. Collector-Emitter voltage (typ.) $T_{j}= 150^{\circ}C$, chip $V_{ce}=20V$ 15V

1200

1000

800

600

400

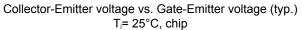
200

0

0.0

1.0

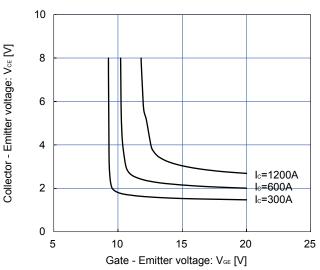
Collector current: Ic [A]

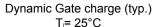


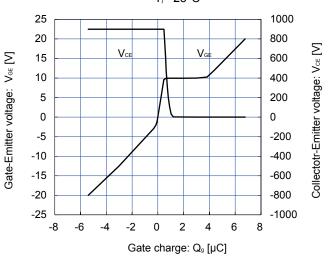
Collector-Emitter voltage: V_{CE} [V]

3.0

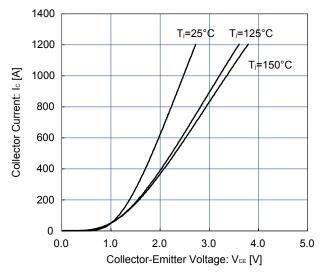
2.0

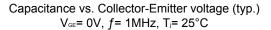


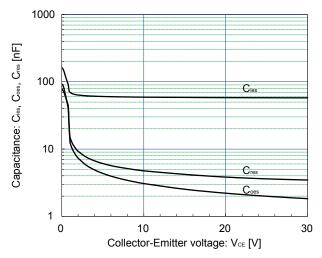




Collector current vs. Collector-Emitter voltage (typ.) V_{GE} = +15V, chip







toff

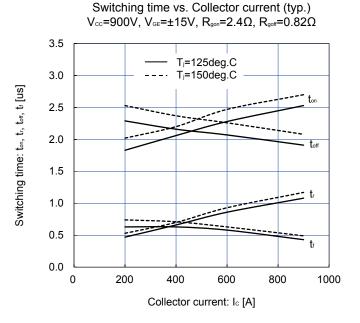
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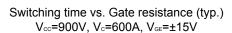
t

tſ

8

7





Tj=125deg.C

Tj=150deg.C

2

3

4.5

4.0

3.5

3.0

2.5

2.0

1.5

1.0

0.5

0.0

0

1

Switching time : ton, tr, tott, tr [us]

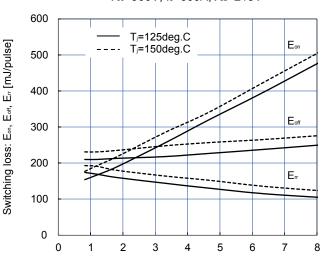


4

Gate resistance : R_g [Ω]

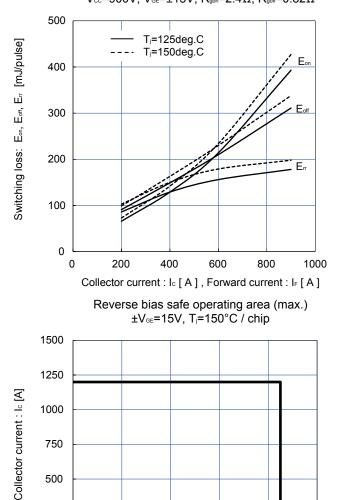
5

6



Gate resistance : R_g [Ω]

Switching loss vs. Collector current (typ.) $V_{cc}=900V, V_{GE}=\pm 15V, R_{gon}=2.4\Omega, R_{goff}=0.82\Omega$



750

500

250

0 0

400

800

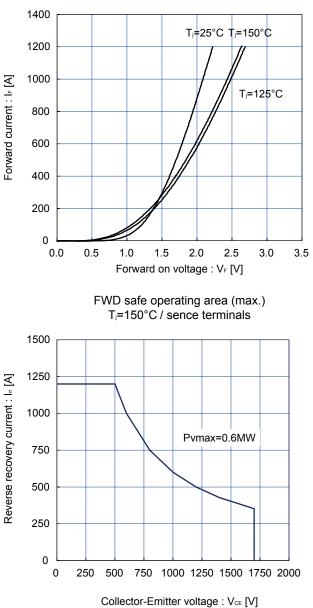
1200

Collector - Emitter voltage : V_{CE} [V]

1600

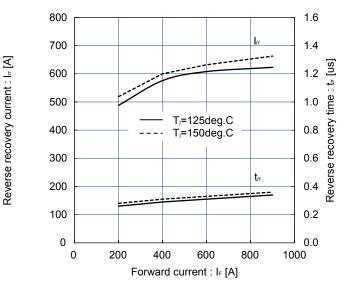


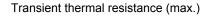
2000

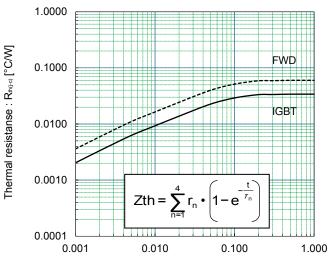


Forward current vs. Forward on voltage (typ.) chip

Reverse recovery characteristics (typ.) V_{CC} =900V, V_{GE} =±15V, R_{gon} =2.4 Ω





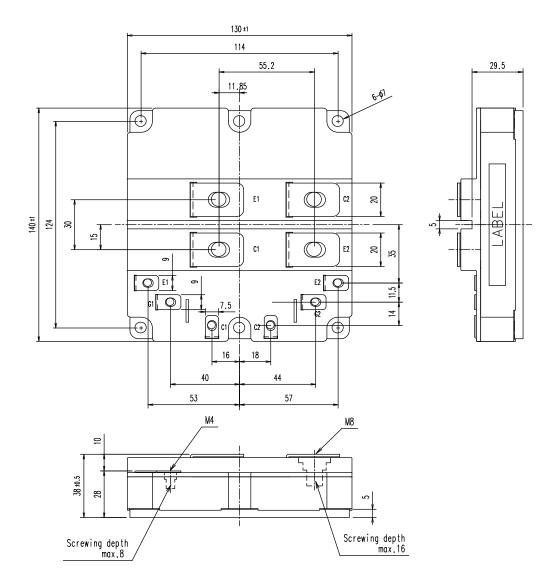


Pulse width : Pw [sec]

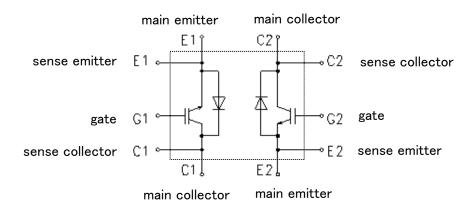
	IGBT	FWD		
r1	0.00383	0.00667		
r1	0.01312	0.02317		
r3	0.00941	0.01659		
r4	0.00764	0.01356		
t1	0.0024	0.0024		
t2	0.0359	0.0355		
t3	0.0627	0.0638		
t4	0.0743	0.0733		

http://www.fujielectric.com/products/semiconductor/

■ Outline Drawing (Unit : mm)



Equivalent circuit



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Nuclear control equipment

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